

25 A standard and Snubberless™ triacs

Features

- High current triac
- Low thermal resistance with clip bonding
- High commutation (4 quadrant) or very high commutation (3 quadrant) capability
- BTA series UL1557 certified (File ref: 81734)
- Packages are RoHS (2002/95/EC) compliant

Applications

Applications include the ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits, etc., or for phase control operation in light dimmers, motor speed controllers, and similar.

The snubberless versions (BTA/BTB...W and T25 series) are especially recommended for use on inductive loads, due to their high commutation performances. The BTA series provides an insulated tab (rated at 2500 V_{RMS}).

Description

Available either in through-hole or surface-mount packages, the **BTA24**, **BTB24**, **BTA25**, **BTA26**, **BTB26** and **T25** triac series is suitable for general purpose mains power AC switching.

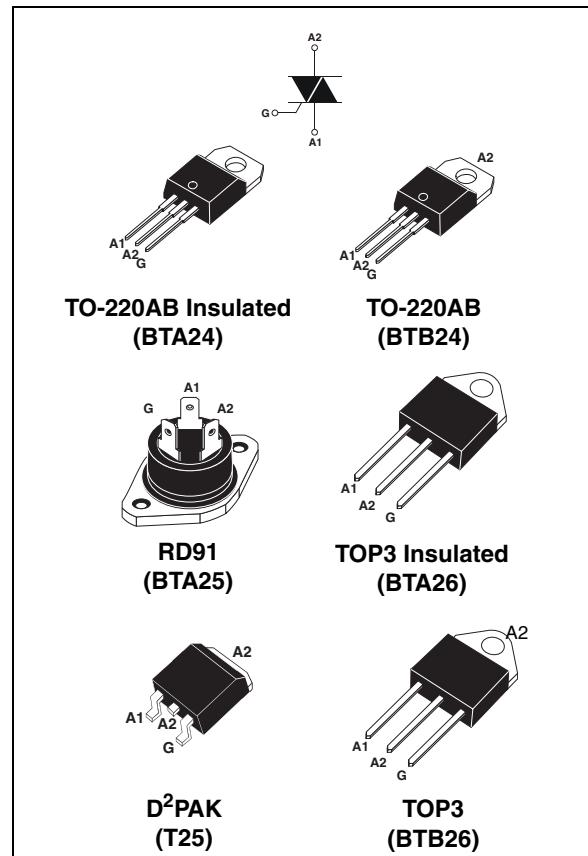


Table 1. Device summary

Symbol	Parameter	BTA24 ⁽¹⁾	BTB24	BTA25 ⁽¹⁾	BTA26 ⁽¹⁾	BTB26	T25	Unit
I _{T(RMS)}	RMS on-state current	25	25	25	25	25	25	A
V _{DRM/V_{RRM}}	Repetitive peak off-state voltage	600 / 700	600 / 700	600 / 700	600 ⁽²⁾ / 700	600	600 / 700	V
I _{GT} (Snubberless)	Triggering gate current	35 / 50	35 / 50	50	35 / 50	-	35	mA
I _{GT} (Standard)	Triggering gate current	-	50	50	50	50	-	mA

1. Insulated packages

2. 600 V version available only with I_{GT} = 50 mA (Snubberless and Standard)

1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	TOP3	$T_c = 105^\circ C$	25	A
		D ² PAK / TO-220AB	$T_c = 100^\circ C$		
		RD91 Ins/ TOP3 Ins.	$T_c = 100^\circ C$		
		TO-220AB Ins.	$T_c = 75^\circ C$		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25° C)	$F = 50$ Hz	$t = 20$ ms	250	A
		$F = 60$ Hz	$t = 16.7$ ms	260	
I^2t	I^2t Value for fusing	$t_p = 10$ ms		340	A ² s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100$ ns	$F = 120$ Hz	$T_j = 125^\circ C$	50	A/ μ s
V_{DSM}/V_{RSM}	Non repetitive surge peak off-state voltage	$t_p = 10$ ms	$T_j = 25^\circ C$	$V_{DRM}/V_{RRM} + 100$	V
I_{GM}	Peak gate current	$t_p = 20$ μ s	$T_j = 125^\circ C$	4	A
$P_{G(AV)}$	Average gate power dissipation	$T_j = 125^\circ C$		1	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	°C

Table 3. Electrical characteristics ($T_j = 25^\circ C$, unless otherwise specified), Snubberless and logic level (3 quadrants) T25, BTA/BTB24...W, BTA25...W, BTA26...W

Symbol	Test Conditions	Quadrant		T25	BTA/BTB		Unit
				T2535	CW	BW	
$I_{GT}^{(1)}$	$V_D = 12$ V $R_L = 33 \Omega$	I - II - III	MAX.	35	35	50	mA
V_{GT}		I - II - III	MAX.	1.3			V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3$ k Ω $T_j = 125^\circ C$	I - II - III	MIN.	0.2			V
$I_H^{(2)}$	$I_T = 500$ mA		MAX.	50	50	75	mA
I_L	$I_G = 1.2 I_{GT}$	I - III	MAX.	70	70	80	mA
		II		80	80	100	
$dV/dt^{(2)}$	$V_D = 67\% V_{DRM}$ gate open	$T_j = 125^\circ C$	MIN.	500	500	1000	V/ μ s
$(dI/dt)c^{(2)}$	Without snubber	$T_j = 125^\circ C$	MIN.	13	13	22	A/ms

1. minimum I_{GT} is guaranteed at 5% of I_{GT} max.

2. for both polarities of A2 referenced to A1.

Table 4. Electrical characteristics ($T_j = 25^\circ C$, unless otherwise specified), standard (4 quadrants), BTB24...B, BTA25...B, BTA26...B, BTB26...B

Symbol	Test Conditions	Quadrant		Value	Unit
$I_{GT}^{(1)}$	$V_D = 12 V$ $R_L = 33 \Omega$	I - II - III	MAX.	50	mA
V_{GT}		IV		100	
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 k\Omega$ $T_j = 125^\circ C$	ALL	MAX.	1.3	V
$I_H^{(2)}$	$I_T = 500 mA$		MAX.	80	mA
I_L	$I_G = 1.2 I_{GT}$	I - III - IV	MAX.	70	mA
		II		160	
$dV/dt^{(2)}$	$V_D = 67 \% V_{DRM}$ gate open	$T_j = 125^\circ C$	MIN.	500	V/ μ s
$(dV/dt)c^{(2)}$	$(dl/dt)c = 13.3 A/ms$	$T_j = 125^\circ C$	MIN.	10	V/ μ s

1. minimum I_{GT} is guaranteed at 5% of I_{GT} max.

2. for both polarities of A2 referenced to A1.

Table 5. Static characteristics

Symbol	Test Conditions		Value	Unit	
$V_{TM}^{(1)}$	$I_{TM} = 35 A$ $t_p = 380 \mu s$	$T_j = 25^\circ C$	MAX.	1.55	V
$V_{t0}^{(1)}$	Threshold voltage	$T_j = 125^\circ C$	MAX.	0.85	V
$R_d^{(1)}$	Dynamic resistance	$T_j = 125^\circ C$	MAX.	16	m Ω
I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM}$	$T_j = 25^\circ C$	MAX.	5	μ A
		$T_j = 125^\circ C$		3	mA

1. for both polarities of A2 referenced to A1.

Table 6. Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	TOP 3	0.6	° C/W
	D ² PAK / TO-220AB	0.8	
	RD91 Insulated / TOP3 Insulated	0.9	
	TO-220AB Insulated	1.7	
$R_{th(j-a)}$	$(1) S = 1 cm^2$	D ² PAK	45
	Junction to ambient	TOP3 / TOP3 Insulated	50
		TO-220AB / TO-220AB Insulated	60

1. S = Copper surface under tab.

Figure 1. Maximum power dissipation versus RMS on-state current (full cycle)

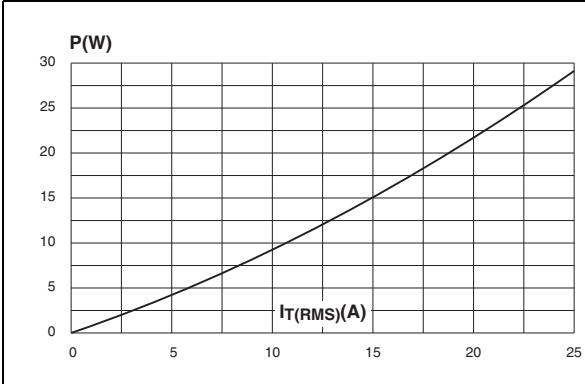


Figure 2. RMS on-state current versus case temperature (full cycle)

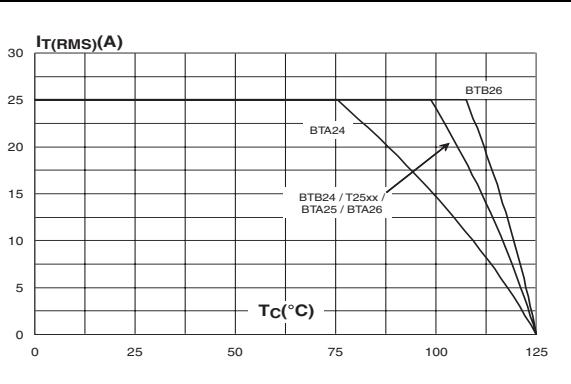


Figure 3. D²PAK RMS on-state current versus ambient temperature (printed circuit board FR4, copper thickness: 35µm) (full cycle)

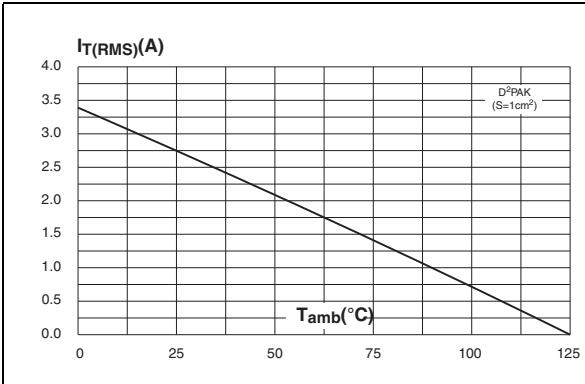


Figure 4. Relative variation of thermal impedance versus pulse duration

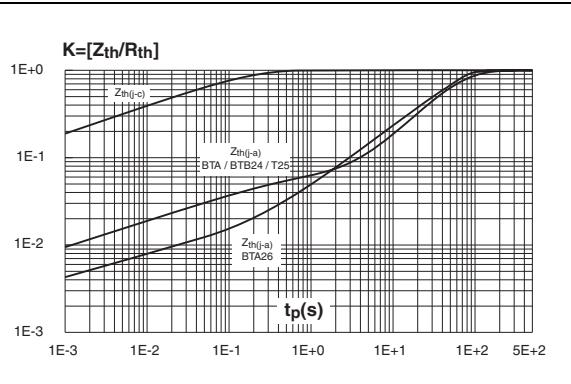


Figure 5. On-state characteristics (maximum values)

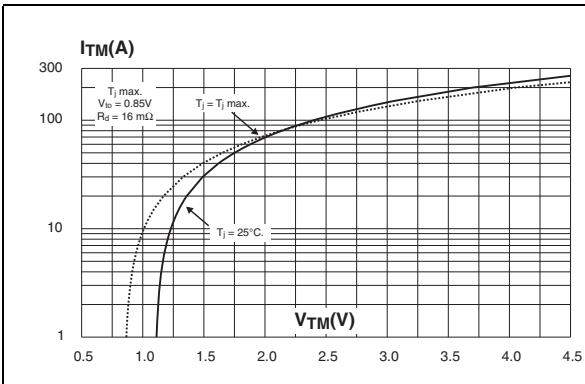


Figure 6. Surge peak on-state current versus number of cycles

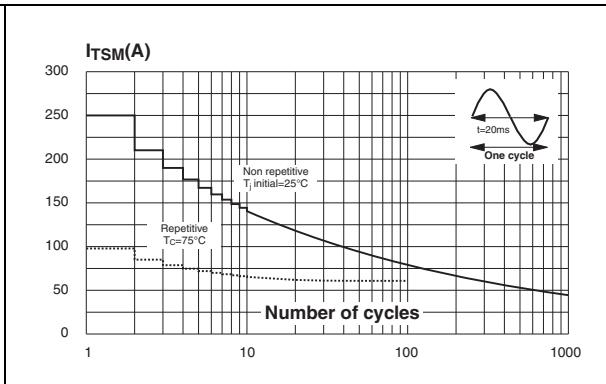


Figure 7. Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms and corresponding value of I^2t

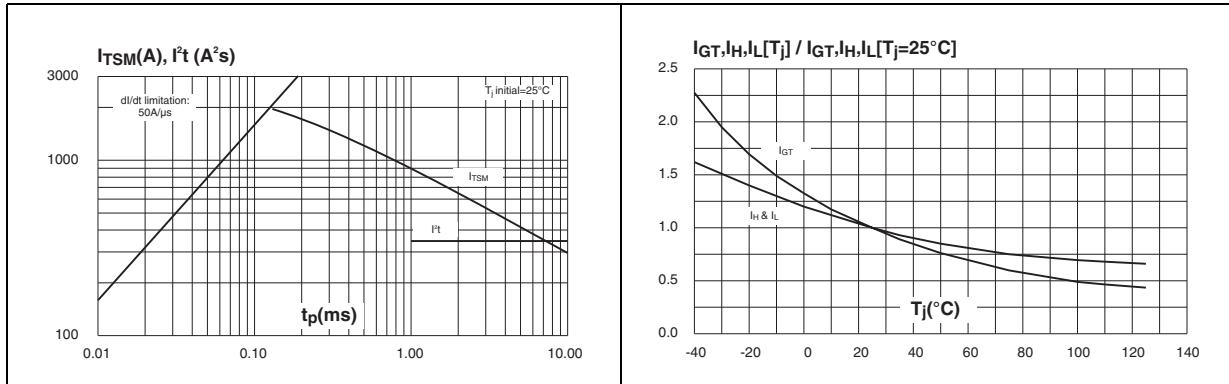


Figure 8. Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

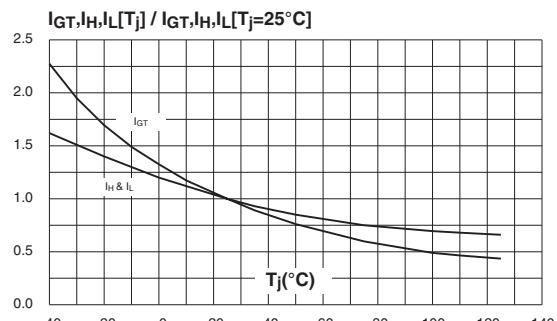


Figure 9. Relative variation of critical rate of decrease of main current versus $(dV/dt)c$ (typical values)

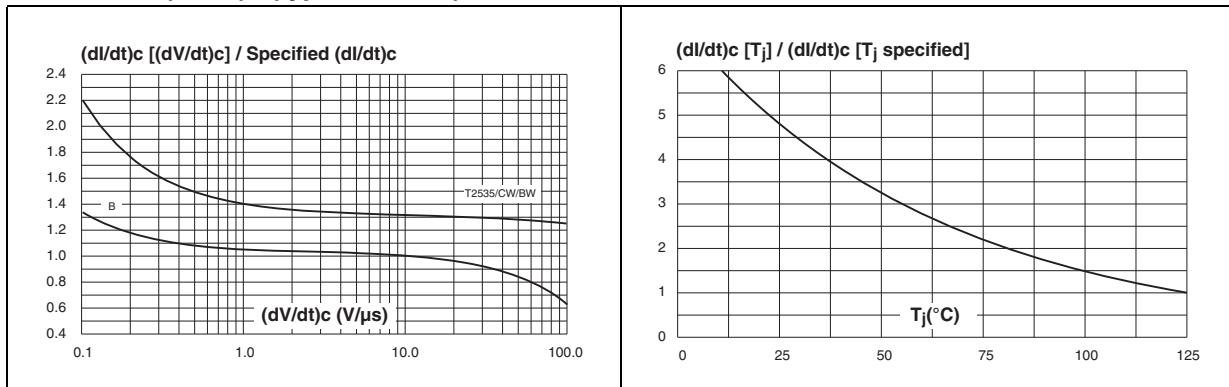


Figure 10. Relative variation of critical rate of decrease of main current versus T_j

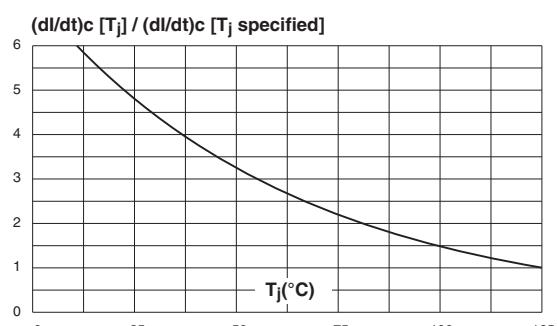
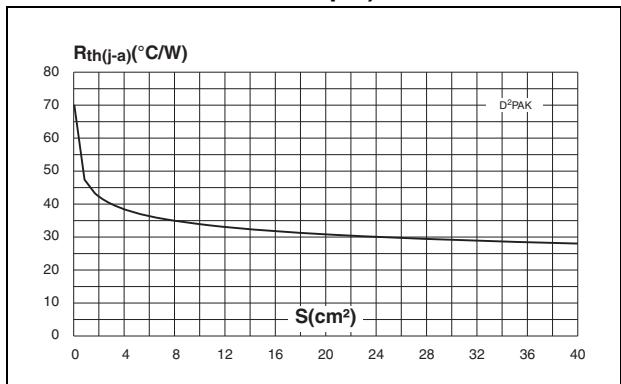


Figure 11. D²PAK thermal resistance junction to ambient versus copper surface under tab (printed circuit board FR4, copper thickness: 35 μm)



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Ordering information scheme

Figure 12. BTA and BTB series

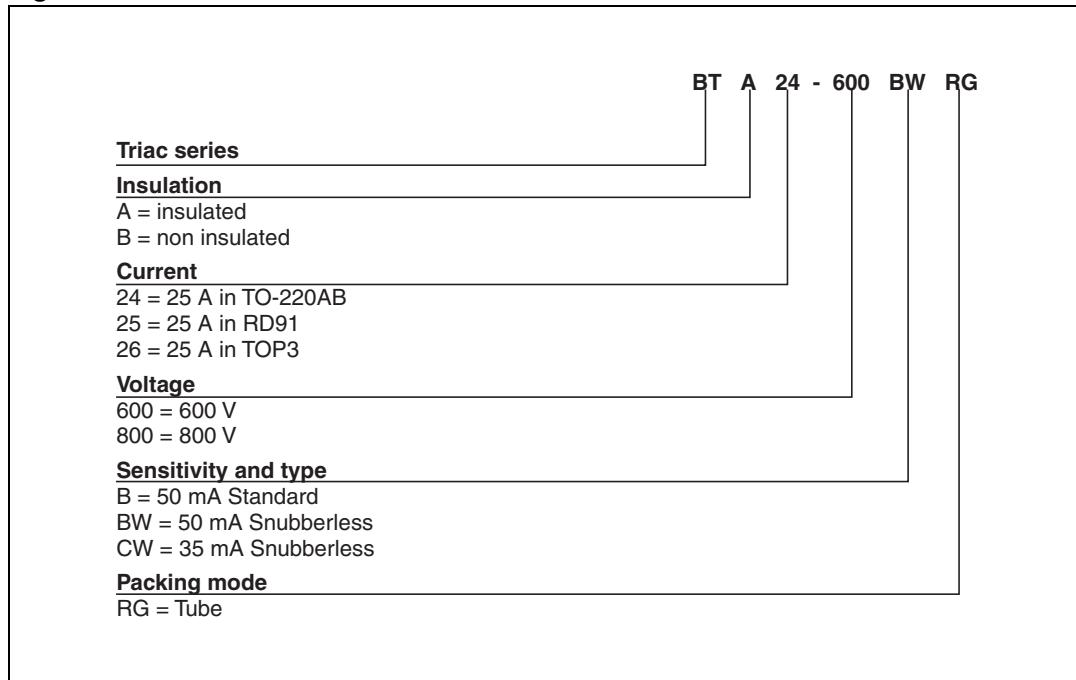
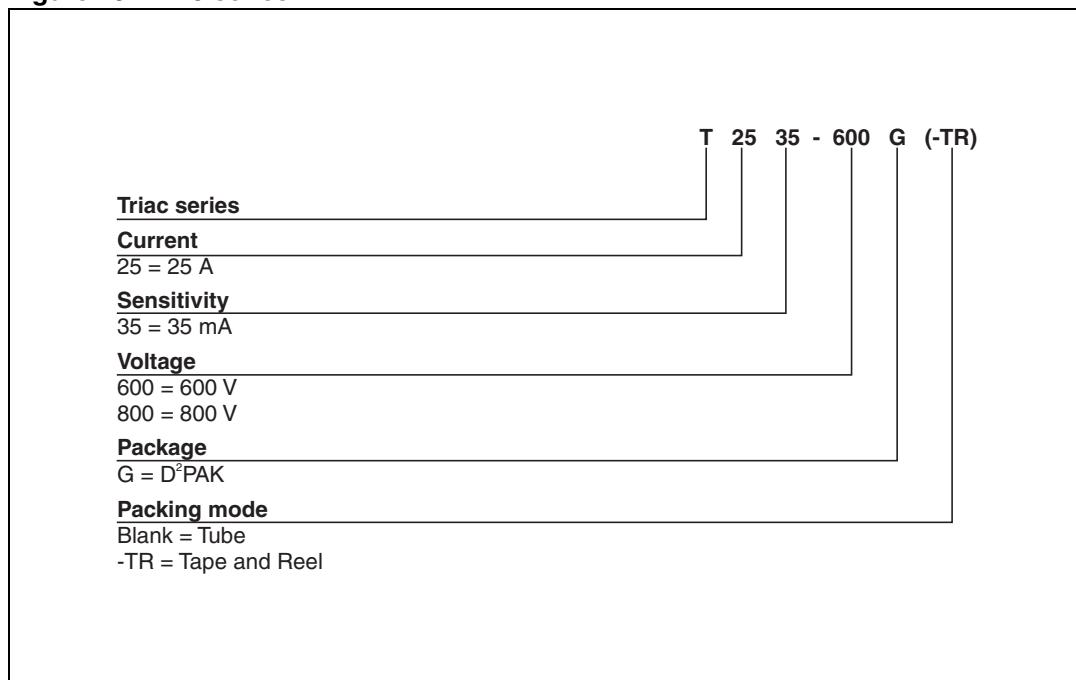


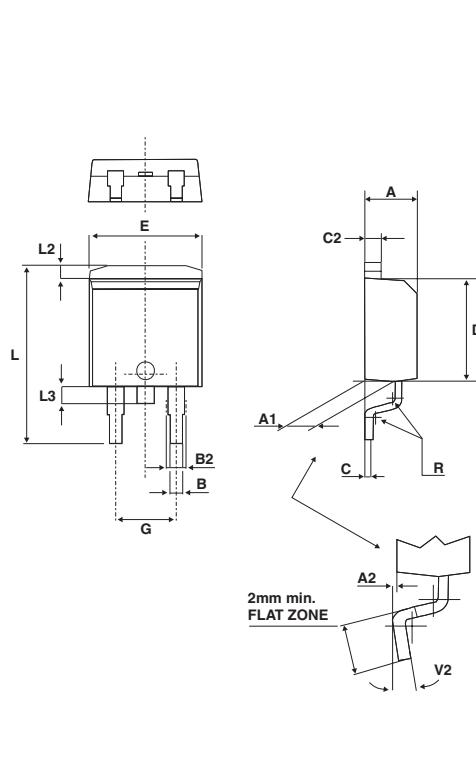
Figure 13. T25 series



3 Package information

- Epoxy meets UL94,V0
- Cooling method: C
- Recommended torque value: 0.4 - 0.5 Nm (TO-220AB), 0.9 - 1.2 Nm (TOP3 and RD91)
- Maximum torque value for BTB24 is 0.5 Nm

Table 7. D²PAK dimensions



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.169		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
B	0.70		0.93	0.027		0.037
B2	1.25	1.40		0.048	0.055	
C	0.45		0.60	0.017		0.024
C2	1.21		1.36	0.047		0.054
D	8.95		9.35	0.352		0.368
E	10.00		10.28	0.393		0.405
G	4.88		5.28	0.192		0.208
L	15.00		15.85	0.590		0.624
L2	1.27		1.40	0.050		0.055
L3	1.40		1.75	0.055		0.069
R		0.40			0.016	
V2	0°		8°	0°		8°

Figure 14. D²PAK footprint dimensions (in millimeters)

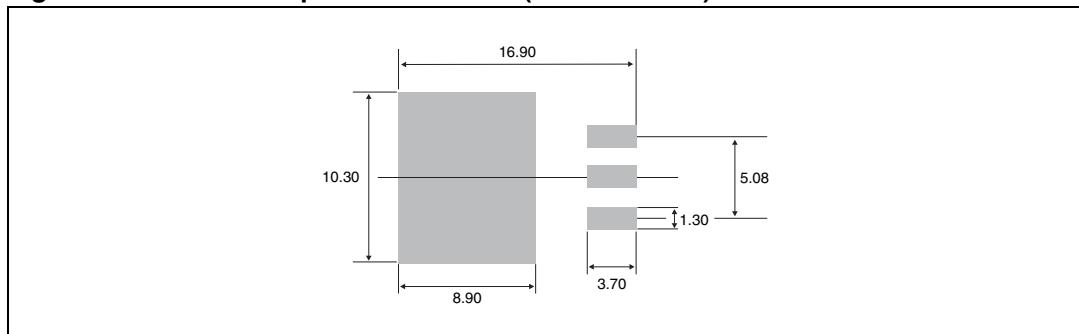
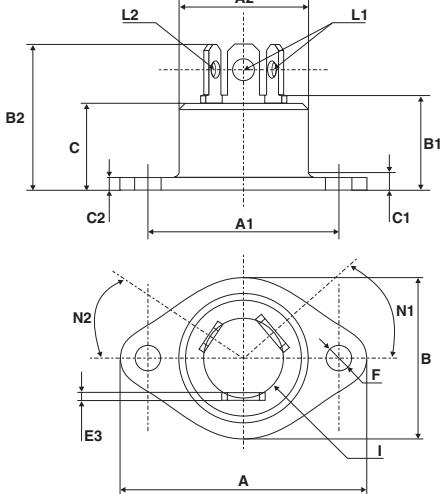


Table 8. RD91 dimensions

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	40.00		1.575	
A1	29.90	30.30	1.177	1.193
A2	22.00		0.867	
B	27.00		1.063	
B1	13.50	16.50	0.531	0.650
B2	24.00		0.945	
C	14.00		0.551	
C1	3.50		0.138	
C2	1.95	3.00	0.077	0.118
E3	0.70	0.90	0.027	0.035
F	4.00	4.50	0.157	0.177
I	11.20	13.60	0.441	0.535
L1	3.10	3.50	0.122	0.138
L2	1.70	1.90	0.067	0.075
N1	33°	43°	33°	43°
N2	28°	38°	28°	38°



The technical drawings show two views of the RD91 component. The top view illustrates a rectangular base with a central vertical slot and two side cutouts. Dimensions include A1 (width of base), A2 (width of central slot), L1 (length of base), L2 (length of central slot), B1 (height of base), B2 (total height), C (depth of base), C1 (depth of side cutout), and C2 (depth of central slot). The bottom view shows a circular part with internal features and dimensions A (outer diameter), B (inner diameter), E3 (width of shoulder), F (width of shoulder), I (width of shoulder), N1 (angle of shoulder), and N2 (angle of shoulder).

Table 9. TOP3 (insulated and non_insulated) dimensions

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.4		4.6	0.173		0.181
B	1.45		1.55	0.057		0.061
C	14.35		15.60	0.565		0.614
D	0.5		0.7	0.020		0.028
E	2.7		2.9	0.106		0.114
F	15.8		16.5	0.622		0.650
G	20.4		21.1	0.815		0.831
H	15.1		15.5	0.594		0.610
J	5.4		5.65	0.213		0.222
K	3.4		3.65	0.134		0.144
ØL	4.08		4.17	0.161		0.164
P	1.20		1.40	0.047		0.055
R		4.60			0.181	

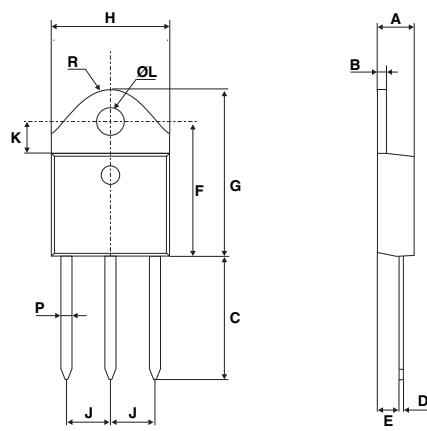
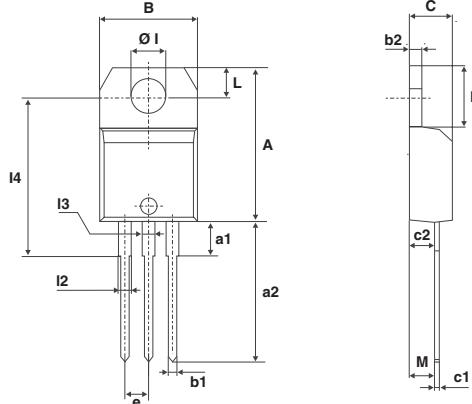


Table 10. TO-220AB (insulated and non-insulated) dimensions

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
Øl	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	



The technical drawing illustrates the physical dimensions of the TO-220AB package. The top view shows the overall height A, lead spacing I4, lead pitch I3, lead thickness I2, lead height I1, and lead width b1. The side cross-section shows the lead thickness e, lead height F, lead width c, lead spacing M, and lead height c2. The top view also includes a circular feature with diameter B and center hole diameter Øl.

4 Ordering information

Table 11. Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BTA/BTB24-xxxxzRG	BTA/BTB24 xxxxz	TO-220AB	2.3 g	50	Tube
BTA25-xxxxz	BTA25xxxxz	RD91	20 g	25	Bulk
BTA26-xxxxRG	BTA26xxxxz	TOP3 Ins.	4.5 g	30	Tube
BTB26-600BRG	BTB26600B	TOP3	4.5 g	30	Tube
T2535-xxxG	T2535 xxxG	D ² PAK	1.5 g	50	Tube
T2535-xxxG-TR	T2535 xxxG			1000	Tape and reel

Note: xxx = voltage, y = sensitivity, z = type